Thyristor High Voltage, Phase Control SCR, 30 A



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PRIMARY CHARACTERISTICS						
I _{T(AV)} 20 A						
V _{DRM} /V _{RRM}	1600 V					
V _{TM}	1.3 V					
I _{GT}	45 mA					
TJ	-40 °C to +125 °C					
Package	TO-247AD 3L					
Circuit configuration	Single SCR					

FEATURES

- Designed and qualified according to JEDEC[®] - JESD 47
- Flexible solution for reliable AC power rectification



HALOGEN

- Easy control peak current at charger power up to reduce passive / electromechanical components
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

APPLICATIONS

• Typical usage is in input rectification crowbar (soft start) and AC switch in motor control, UPS, welding and battery charge

DESCRIPTION

The VS-30TPS16L-M3 high voltage series of silicon controlled rectifiers are specifically designed for medium power switching and phase control applications. AEC-Q101 qualified P/N available (VS-30TPS16LHM3).

MAJOR RATINGS AND CHARACTERISTICS						
PARAMETER	TEST CONDITIONS	VALUES	UNITS			
I _{T(AV)}	Sinusoidal waveform	20	Α			
I _{RMS}		30	A			
V _{RRM} /V _{DRM}		1600	V			
I _{TSM}		300	A			
V _T	20 A, T _J = 25 °C	1.3	V			
dv/dt		500	V/µs			
di/dt		150	A/µs			
TJ		-40 to +125	°C			

VOLTAGE RATINGS								
PART NUMBER	V _{RRM} /V _{DRM} , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} /I _{DRM} AT 125 °C mA					
VS-30TPS16L-M3	1600	1700	10					

VS-30TPS16L-M3



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ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CON	NDITIONS	VALUES	UNITS
Maximum average on-state current	I _{T(AV)}	$T_C = 95 \ ^{\circ}C$, 180° conduction	half sine wave	20	
Maximum RMS on-state current	I _{RMS}			30	А
Maximum peak, one-cycle,		10 ms sine pulse, rated V_{RRM}	applied	250	A
non-repetitive surge current	I _{TSM}	10 ms sine pulse, no voltage	reapplied	300	
Maximum I ² t for fusing	l ² t	10 ms sine pulse, rated V_{RRM}	applied	310	A ² s
Maximum - t for fusing	1-1	10 ms sine pulse, no voltage reapplied		442	A-S
Maximum I ² √t for fusing	l²√t	t = 0.1 to 10 ms, no voltage reapplied		4420	A²√s
Maximum on-state voltage drop	V _{TM}	20 A, T _J = 25 °C		1.3	V
On-state slope resistance	r _t	T 405 00		12	mΩ
Threshold voltage	V _{T(TO)}	T _J = 125 °C		1.0	V
Maximum reverse and direct leakage current	I _{RM} /I _{DM}	T _J = 25 °C	$V_{B} = rated V_{BBM}/V_{DBM}$	0.5	
Maximum reverse and direct leakage current	'RM' 'DM	$T_J = 125 \text{ °C}$		10	mA
Maximum holding current	Ι _Η	Anode supply = 6 V, resistive load, initial I_T = 1 A, T_J = 25 °C		150	IIIA
Maximum latching current	١L	Anode supply = 6 V, resistive load, $T_J = 25 \text{ °C}$		200	
Maximum rate of rise of off-state voltage	dv/dt	$T_J = T_J$ maximum, linear to 80) % V_{DRM} , $R_g - k = open$	500	V/µs
Maximum rate of rise of turned-on current	di/dt			150	A/µs

TRIGGERING						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum peak gate power	P _{GM}		8.0	w		
Maximum average gate power	P _{G(AV)}		2.0	vv		
Maximum peak positive gate current	+I _{GM}		1.5	А		
Maximum peak negative gate voltage	-V _{GM}		10	V		
	I _{GT}	Anode supply = 6 V, resistive load, T_J = -10 °C	60	mA		
Maximum required DC gate current to trigger		Anode supply = 6 V, resistive load, $T_J = 25 \ ^{\circ}C$	45			
		Anode supply = 6 V, resistive load, $T_J = 125 \text{ °C}$	20			
Maximum required DO acts		Anode supply = 6 V, resistive load, $T_J = -10 \ ^{\circ}C$	2.5			
Maximum required DC gate voltage to trigger	V _{GT}	Anode supply = 6 V, resistive load, $T_J = 25 \degree C$ 2.0				
		Anode supply = 6 V, resistive load, $T_J = 125 \text{ °C}$	1.0	V		
Maximum DC gate voltage not to trigger		T _{.I} = 125 °C, V _{DBM} = rated value	0.25			
Maximum DC gate current not to trigger	I _{GD}	$i_{\rm J} = i_{\rm ZS}$ O, $v_{\rm DRM} = i_{\rm ateu} v_{\rm alue}$	2.0	mA		

SWITCHING						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Typical turn-on time	t _{gt}	T _J = 25 °C	0.9			
Typical reverse recovery time	t _{rr}	T ₁ = 125 °C	4	μs		
Typical turn-off time	tq	ij=125 C	110			



THERMAL AND MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL TEST CONDITIONS		VALUES	UNITS	
Maximum junction and storage temperature range		T _J , T _{Stg}		-40 to 125	°C	
Maximum thermal resistance, junction to case		R _{thJC}	DC operation	0.8		
Maximum thermal resistance, junction to ambient		R _{thJA}		40	°C/W	
Maximum thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.25		
Approximate weight				6	g	
Approximate weight				0.21	oz.	
Mounting torque	minimum			6 (5)	kgf ⋅ cm	
	maximum			12 (10)	(lbf ⋅ in)	
Marking device			Case style TO-247AD 3L	30TP	S16L	

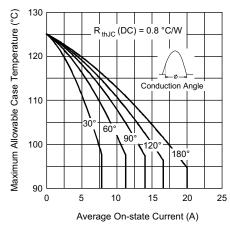


Fig. 1 - Current Rating Characteristics

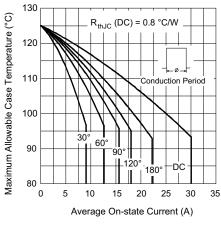


Fig. 2 - Current Rating Characteristics

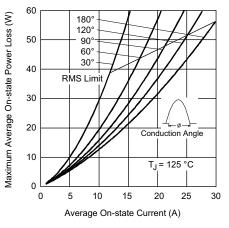
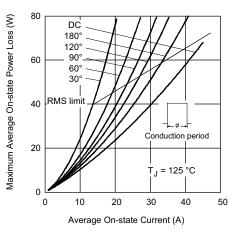
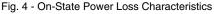


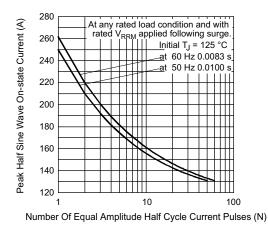
Fig. 3 - On-State Power Loss Characteristics





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Fig. 5 - Maximum Non-Repetitive Surge Current

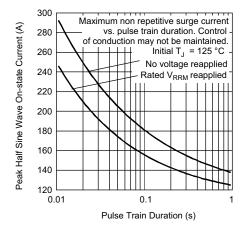


Fig. 6 - Maximum Non-Repetitive Surge Current

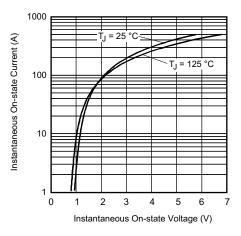


Fig. 7 - On-State Voltage Drop Characteristics

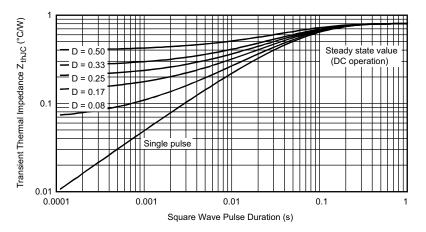
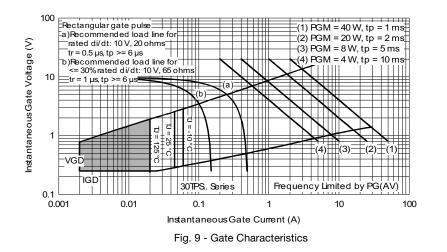


Fig. 8 - Thermal Impedance Z_{thJC} Characteristics



ORDERING INFORMATION TABLE

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SHA

1 2 3 4 5 6 7 8 1 - Vishay Semiconductors product 2 - Current rating $(30 = 30 \text{ A})$ 3 - Circuit configuration: T = thyristor 4 - Package:
 Current rating (30 = 30 Å) Circuit configuration: T = thyristor
 Current rating (30 = 30 Å) Circuit configuration: T = thyristor
T = thyristor
4 - Package:
P = TO-247
5 - Type of silicon:
S = standard recovery rectifier
6 - Voltage rating (16 = 1600 V)
7 - Package L = long lead
8 - Environmental digit:
-M3 = halogen-free, RoHS-compliant, and terminat

ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-30TPS16L-M3	25	500	Antistatic plastic tubes				

LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95626				
Part marking information	www.vishay.com/doc?95007				

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TO-247AD 3L

DIMENSIONS in millimeters and inches



View B

SYMBOL	MILLIN	IETERS	INCHES		NOTES
STIVIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.65	5.31	0.183	0.209	
A1	2.21	2.59	0.087	0.102	
A2	1.50	2.49	0.059	0.098	
b	0.99	1.40	0.039	0.055	
b1	0.99	1.35	0.039	0.053	
b2	1.65	2.39	0.065	0.094	
b3	1.65	2.34	0.065	0.092	
b4	2.59	3.43	0.102	0.135	
b5	2.59	3.38	0.102	0.133	
с	0.38	0.89	0.015	0.035	
c1	0.38	0.84	0.015	0.033	
D	19.71	20.70	0.776	0.815	3
D1	13.08	-	0.515	-	4

(2, 52, 51) (4) Section C - C, D - D, E - E

SYMBOL	MILLIN	MILLIMETERS INCHES		MILLIMETERS I	INCHES		NOTES
STNIBOL	MIN.	MAX.	MIN.	MAX.	NOTES		
D2	0.51	1.30	0.020	0.051			
E	15.29	15.87	0.602	0.625	3		
E1	13.46	-	0.53	-			
е	5.46	BSC	0.215	5 BSC			
ØК	0.2	254	0.0)10			
L	19.81	20.32	0.780	0.800			
L1	3.71	4.29	0.146	0.169			
ØΡ	3.56	3.66	0.14	0.144			
Ø P1	-	6.98	-	0.275			
Q	5.31	5.69	0.209	0.224			
R	4.52	5.49	0.178	0.216			
S	5.51	BSC	0.217	' BSC			

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5M-1994

(2) Contour of slot optional

- ⁽³⁾ Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- ⁽⁵⁾ Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- ⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4

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